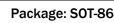
SGA6386Z



rfmd.com

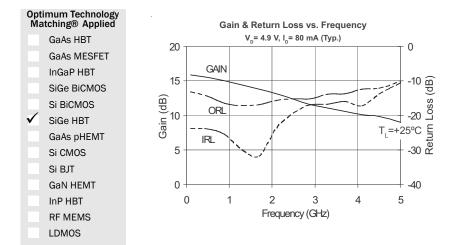
DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER





Product Description

The SGA6386Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- Broadband Operation: DC to 5000 MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition
	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	14.0	15.4	16.9	dB	850MHz
		13.5		dB	1950MHz
		12.5		dB	2400MHz
Output Power at 1dB Compression		21.0		dBm	850MHz
		19.0		dBm	1950MHz
Output Third Intercept Point		36.0		dBm	850MHz
		34.0		dBm	1950MHz
Bandwidth Determined by Return Loss		5000		MHz	>10dB
Input Return Loss		26.7		dB	1950MHz
Output Return Loss		16.2		dB	1950MHz
Noise Figure		4.0		dB	1950MHz
Device Operating Voltage	4.6	4.9	5.4	V	
Device Operating Current	72	80	88	mA	
Thermal Resistance (Junction - Lead)		97		°C/W	

Test Conditions: $V_S = 8V$, $I_D = 80$ mA Typ., OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=0dBm, $R_{BIAS} = 39\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$

RF MICRO DEVICES®, RFMD®, Optimum Technology Matching®, Enabling Wireless Connectivity¹⁰, PowerStar®, POLARIS¹⁰ TOTAL RADIO¹⁰ and UttimateBlue¹⁰ are trademarks of RFMD, LLC. BLUETOOTH is a trademark owned by Bluetooth SIG, Inc., U.S.A. and licensed for use by RFMD. All other trade manes, trademarks and recistered trademarks are the nonnerty of their respective owners. ©2016 RF Mirror Devices Inc.

SGA6386Z



Absolute Maximum Ratings

Parameter	Rating	Unit			
Max Device Current (I _D)	160	mA			
Max Device Voltage (V _D)	7	V			
Max RF Input Power	+18	dBm			
Max Junction Temp (T _J)	+150	°C			
Operating Temp Range (T _L)	-40 to +85	°C			
Max Storage Temp	+150	°C			

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Typical Performance at Key Operating Frequencies

Caution! ESD sensitive device.

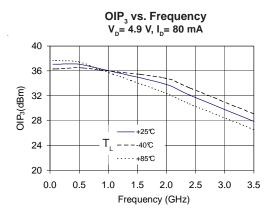
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

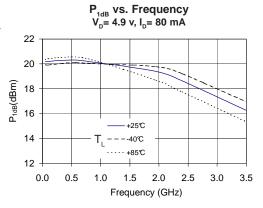
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

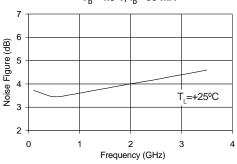
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	15.9	15.5	15.4	13.5	12.5	10.7
Output Third Order Intercept Point	dBm	37.1	37.1	36.0	34.0	32.2	27.9
Output Power at 1dB Compression	dBm	20.2	20.5	21.0	19.0	18.6	16.3
Input Return Loss	dB	23.8	23.9	25.6	26.7	20.4	16.0
Output Return Loss	dB	13.2	14.5	16.6	16.2	15.1	14.2
Reverse Isolation	dB	20.0	20.2	20.4	19.9	19.2	17.2
Noise Figure	dB	3.7	3.4	3.6	4.0	4.2	4.6

Test Conditions: $V_S = 8V$, $I_D = 80$ mA Typ., OIP₃ Tone Spacing = 1 MHz, P_{OUT} per tone = 0 dBm, $R_{BIAS} = 39\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



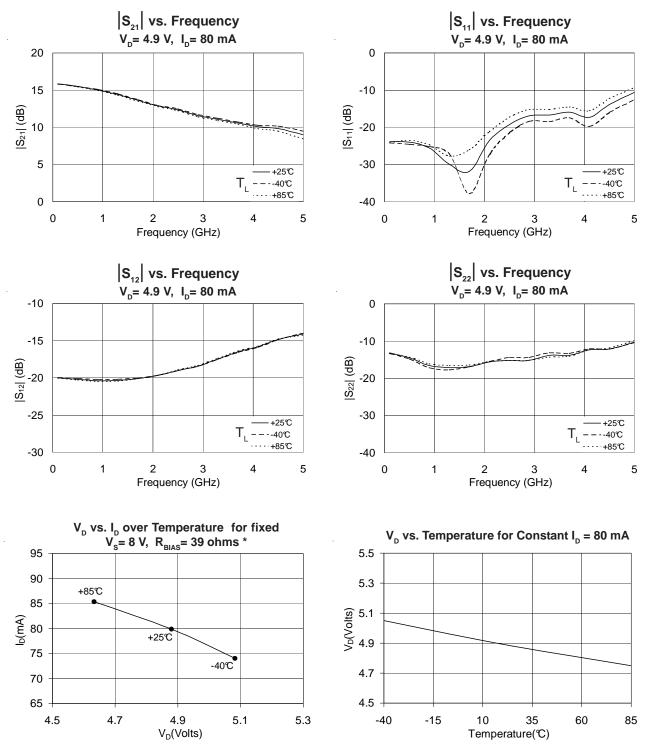


Noise Figure vs. Frequency $V_{p} = 4.9 \text{ V}, I_{p} = 80 \text{ mA}$









* Note: In the applications circuit on page 4, R_{BIAS} compensates for voltage and current variation over temperature.

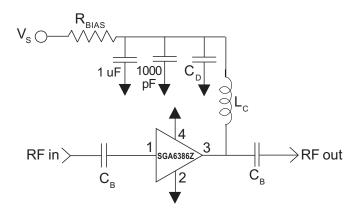
SGA6386Z

RFMD ໜ

rfmd.com

Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC-blocking capacitor is necessary for proper oper- ation.

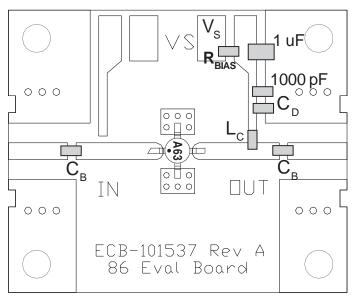
Application Schematic



Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C _B	220 pF	100 pF	68 pF	56 pF	39 pF		
C _D	100 pF	68 pF	22 pF	22 pF	15 pF		
L _c	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for I_{D} =80mA R_{BIAS} =(V _S -V _D) / I_{D}				
Supply Voltage(V _s)	6 V	8 V	10 V	12 V
R _{BIAS} 13 Ω 39 Ω 62 Ω 91 Ω				
Note: $R_{_{BIAS}}$ provides DC bias stability over temperature.				

Evaluation Board Layout

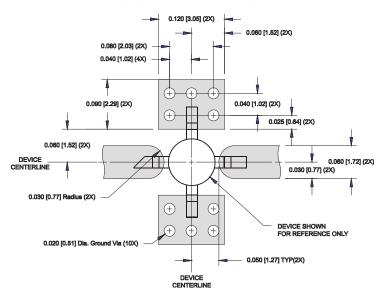


Mounting Instructions

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- 3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.



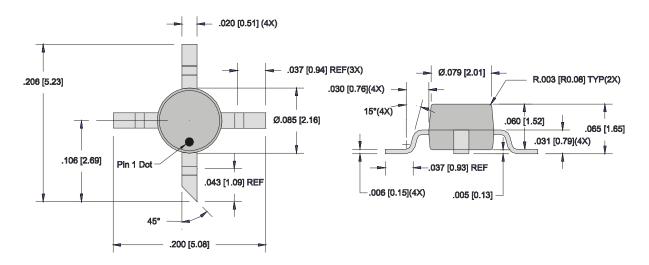




Suggested Pad Layout

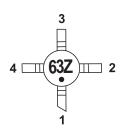
Package Drawing

Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.





Part Identification



Ordering Information

Ordering Code	Description
SGA6386Z	13" Reel with 3000 pieces
SGA6386ZSQ	Sample bag with 25 pieces
SGA6386ZSR	7" Reel with 100 pieces
SGA6386ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag